



DO-41 Plastic-Encapsulate Transistors

FR101 THRU FR107

VOLTAGE RANGE
CURRENT

50 to 1000 Volts
1.0 Ampere

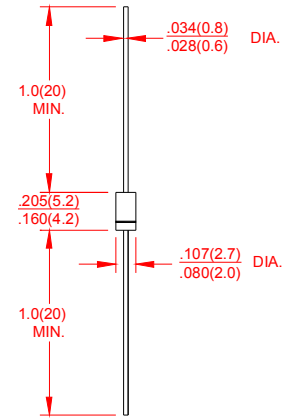
DO-41

FEATURES

- Low coat construction
- Fast switching for high efficiency.
- Low reverse leakage
- High forward surge current capability
- High temperature soldering guaranteed:
260°C/10 secods/.375”(9.5mm)lead length at 5 lbs(2.3kg) tension

MECHANICAL DATA

- Case: Transfer molded plastic
- Epoxy: UL94V-O rate flame retardant
- Polarity: Color band denotes cathode end
- Lead: Plated axial lead, solderable per MIL-STD-202E method 208C
- Mounting position: Any
- Weight: 0.012 ounce, 0.33 grams



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

- Ratings at 25°C ambient temperature unless otherwise specified
- Single Phase, half wave, 60Hz, resistive or inductive load
- For capacitive load derate current by 20%

	SYMBOLS	FR101	FR102	FR103	FR104	FR105	FR106	FR107	UNITS
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current 0.375”(9.5mm) lead length at $T_A=75^\circ\text{C}$	$I_{(AV)}$	1.0							Amp
Peak Forward Surge Current 8.3mS single half sine wave superimposed on rated load (JEDEC method)	I_{FSM}	30							Amps
Maximum Instantaneous Forward Voltage @ 1.0A	V_F	1.3							Volts
Maximum DC Reverse Current at Rated DC Blocking Voltage	$T_A=25^\circ\text{C}$	5.0							μA
	$T_A=100^\circ\text{C}$	100							
Maximum Reverse Recovery Time (Note 3) $T_J=25^\circ\text{C}$	t_{rr}	150				250	500		ns
Typical Junction Capacitance (Note 1)	C_J	15							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	50							$^\circ\text{C}/\text{W}$
Operating Junction Temperature Range	T_J	(-55 to +150)							$^\circ\text{C}$
Storage Temperature Range	T_{STG}	(-55 to +150)							$^\circ\text{C}$

Notes:

1. Measured at 1.0MHz and Applied Reverse Voltage of 4.0Volts.
2. Thermal Resistance from junction to Ambient at .375”(9.5mm)lead length, P.C.board mounted.
3. Reverse Recovery Test Conditions: $I_f=0.5\text{A}$, $I_r=1.0\text{A}$, $I_{rr}=0.25\text{A}$



DO-41 Plastic-Encapsulate Transistors

FR101 THRU FR107

VOLTAGE RANGE
CURRENT

50 to 1000 Volts
1.0 Ampere

RATING AND CHARACTERISTIC CURVES FR101 THRU FR107

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

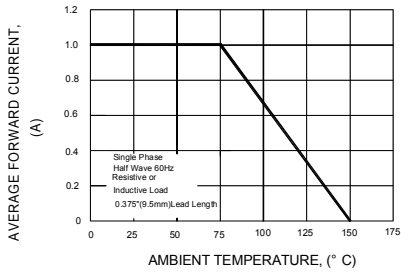


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

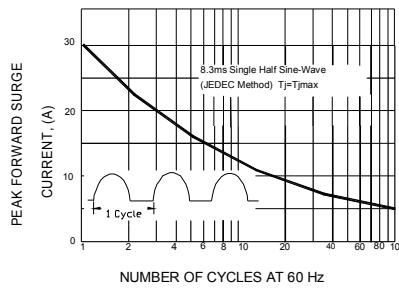


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

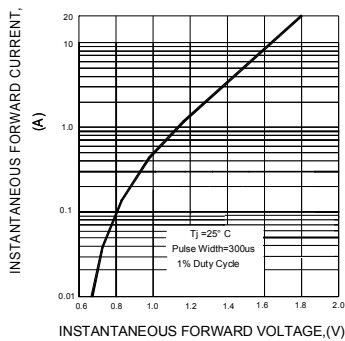


FIG.4-TYPICAL REVERSE CHARACTERISTICS

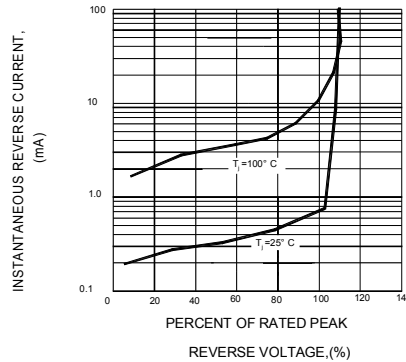


FIG.5-TYPICAL JUNCTION CAPACITANCE

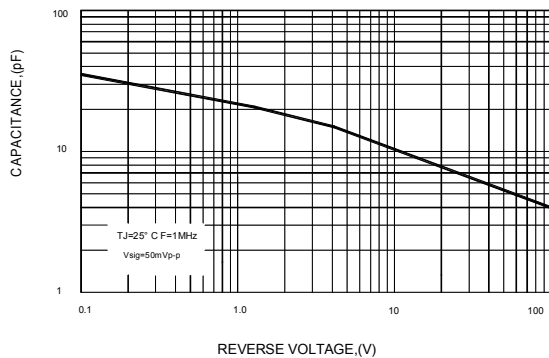
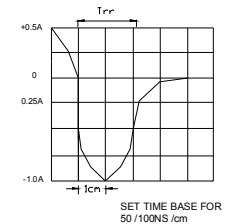
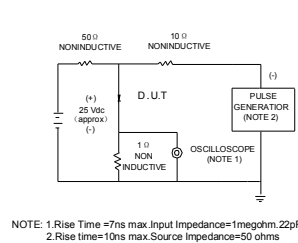


FIG.6-TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTE: 1. Rise Time = 7ns max. Input Impedance=1megohm. 22pF
2. Rise time=10ns max. Source Impedance=50 ohms

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Diodes - General Purpose, Power, Switching category](#):

Click to view products by [HL manufacturer](#):

Other Similar products are found below :

[MMBD3004S-13-F](#) [RD0306T-H](#) [DSE010-TR-E](#) [BAV17-TR](#) [BAV19-TR](#) [1N3611](#) [NTE156A](#) [NTE574](#) [NTE6244](#) [1SS181-TP](#) [1SS193,LF](#)
[1SS400CST2RA](#) [SDAA13](#) [SHN2D02FUTW1T1G](#) [LS4151GS08](#) [FC903-TR-E](#) [1N4449](#) [1N456A](#) [1N4934-E3/73](#) [1N914B](#) [1N914BTR](#)
[1SS226-TP](#) [RFUH20TB3S](#) [D291S45T](#) [BAV300-TR](#) [BAW56DWQ-7-F](#) [BAW75-TAP](#) [MM230L-CAA](#) [IDW40E65D1](#) [JAN1N3600](#) [LL4151-](#)
[GS18](#) [053684A](#) [SMMSD4148T3G](#) [707803H](#) [NSVDAN222T1G](#) [CDSZC01100-HF](#) [LL4150-M-08](#) [1N4454-TR](#) [BAV199E6433HTMA1](#)
[BAS28-7](#) [BAW56HDW-13](#) [BAS28 TR](#) [VS-HFA04SD60STR-M3](#) [NSVM1MA152WKT1G](#) [RGP30D-E3/73](#) [BAV99TQ-13-F](#) [BAS21DWA-7](#)
[NTE6250](#) [NTE582-4](#) [NTE582-6](#)